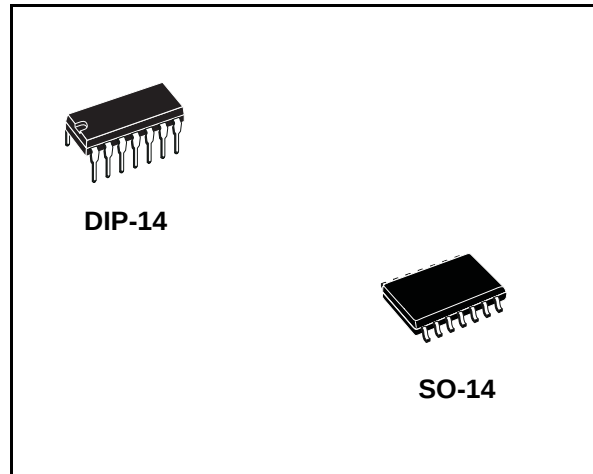


Features

- High speed:
 $t_{PD} = 11 \text{ ns (typ.) at } V_{CC} = 4.5 \text{ V}$
- Low power dissipation:
 $I_{CC} = 1 \mu\text{A (max.) at } T_A = 25 \text{ }^\circ\text{C}$
- Compatible with TTL outputs:
 $V_{IH} = 2 \text{ V (min.) } V_{IL} = 0.8 \text{ V (max)}$
- Balanced propagation delays:
 $t_{PLH} \cong t_{PHL}$
- Symmetrical output impedance:
 $|I_{OH}| = I_{OL} = 4 \text{ mA (min)}$
- Pin and function compatible with 74 series 04



Description

The M74HCT04 is a high speed CMOS hex inverter fabricated with silicon gate C²MOS technology.

The internal circuit is composed of 3 stages including a buffer output, which enables high noise immunity and stable output.

The M74HCT04 is designed to directly interface HSC²MOS systems with TTL and NMOS components.

All inputs are equipped with protection circuits against static discharge and transient excess voltage.

Table 1. Device summary

Order code	Package	Packing
M74HCT04B1R	DIP-14	Tube
M74HCT04RM13TR	SO-14	Tape and reel

1 Pin connection and IEC logic symbols

Figure 1. Pin connections and IEC logic symbols

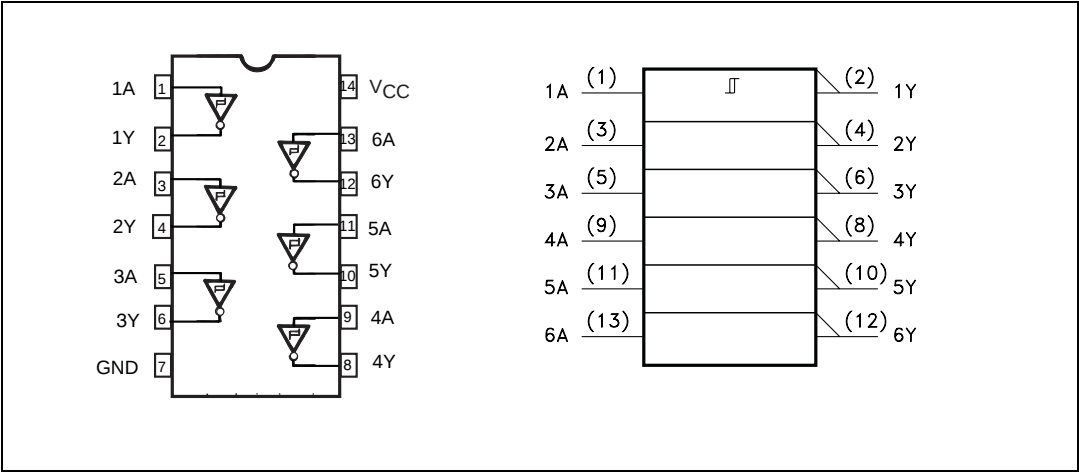


Table 2. Pin description

Pin number	Symbol	Name and function
1, 3, 5, 9, 11, 13	1A to 6A	Data inputs
2, 4, 6, 8, 10, 12	1Y to 6Y	Data outputs
7	GND	Ground (0 V)
14	V _{CC}	Positive supply voltage

Figure 2. Input and output equivalent circuit

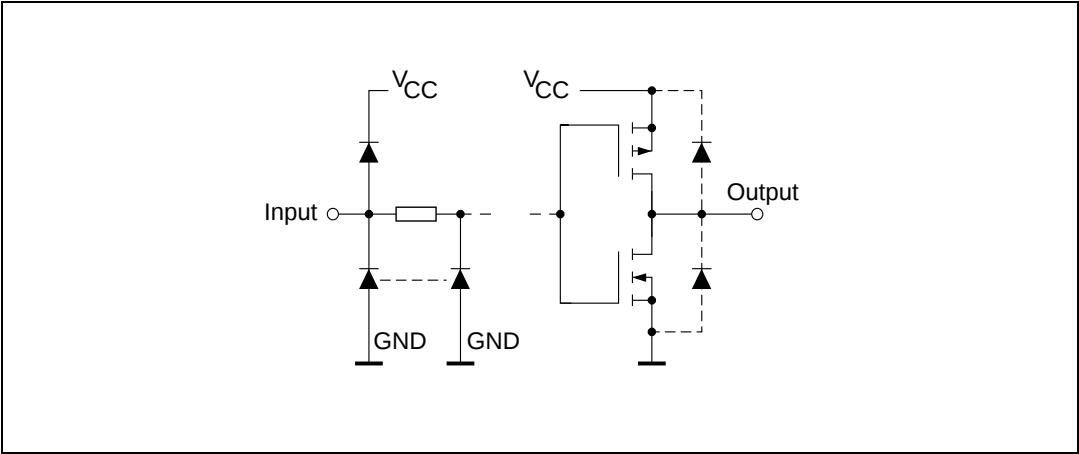


Table 3. Truth table

A	Y
L	H
H	L

2 Maximum rating

Stressing the device above the rating listed in the “Absolute maximum ratings” table may cause permanent damage to the device. These are stress ratings only, and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics SURE Program and other relevant quality documents.

Table 4. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CC}	Supply voltage	-0.5 to +7	V
V_I	DC input voltage	-0.5 to $V_{CC} + 0.5$	V
V_O	DC output voltage	-0.5 to $V_{CC} + 0.5$	V
I_{IK}	DC input diode current	± 20	mA
I_{OK}	DC output diode current	± 20	mA
I_O	DC output current	± 25	mA
I_{CC} or I_{GND}	DC V_{CC} or Ground current	± 50	mA
P_D	Power dissipation	500 ⁽¹⁾	mW
T_{stg}	Storage temperature	-65 to +150	°C
T_L	Lead temperature (10 sec)	300	°C

1. 500 mW at 65 °C; derate to 300 mW by 10 mW/°C from 65 °C to 85 °C

Table 5. Recommended operating conditions

Symbol	Parameter	Value	Unit
V_{CC}	Supply voltage	4.5 to 5.5	V
V_I	Input voltage	0 to V_{CC}	V
V_O	Output voltage	0 to V_{CC}	V
T_{op}	Operating temperature	-55 to 125	°C
t_r, t_f	Input rise and fall time ($V_{CC} = 4.5$ to 5.5 V)	0 to 500	ns

Table 6. DC specifications

Symbol	Parameter	Test condition		Value						Unit	
		V _{CC} (V)		T _A = 25 °C			-40 to 85°C		-55 to 125°C		
				Min	Typ	Max	Min	Max	Min		Max
V _{IH}	High level input voltage	4.5 to 5.5		2.0			2.0		2.0		V
V _{IL}	Low level input voltage	4.5 to 5.5				0.8		0.8		0.8	V
V _{OH}	High level output voltage	4.5	I _O = -20 μA	4.4	4.5		4.4		4.4		V
			I _O = -4.0 mA	4.18	4.31		4.13		4.10		
V _{OL}	Low level output voltage	4.5	I _O = 20 μA		0.0	0.1		0.1		0.1	V
			I _O = 4.0 mA		0.17	0.26		0.33		0.40	
I _I	Input leakage current	5.5	V _I = V _{CC} or GND			±0.1		±1		±1	μA
I _{CC}	Quiescent supply current	5.5	V _I = V _{CC} or GND			1		10		20	μA
Δ I _{CC}	Additional worst case supply current	5.5	Per input pin V _I = 0.5 V or V _I = 2.4 V Other inputs at V _{CC} or GND I _O = 0			2.0		2.9		3.0	mA

Table 7. AC electrical characteristics (C_L = 50 pF, input t_r = t_f = 6 ns)

Symbol	Parameter	Test condition		Value						Unit	
		V _{CC} (V)		T _A = 25°C			-40 to 85°C		-55 to 125°C		
				Min.	Typ.	Max.	Min.	Max.	Min.		Max.
t _{TLH} t _{THL}	Output transition time	4.5			8	15		19		23	ns
t _{PLH} t _{PHL}	Propagation delay time	4.5			11	18		23		27	ns

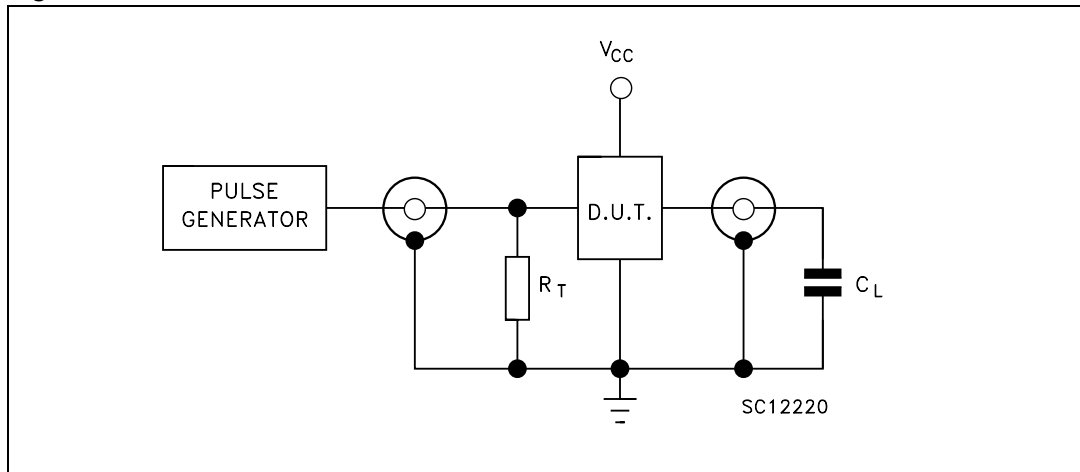
Table 8. Capacitive characteristics

Symbol	Parameter	Test condition		Value							Unit
		V _{CC} (V)		T _A = 25°C			-40 to 85°C		-55 to 125°C		
				Min	Typ	Max	Min	Max	Min	Max	
C _{IN}	Input capacitance				5	10		10		10	pF
C _{PD}	Power dissipation capacitance ⁽¹⁾				20						pF

1. C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation.
 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/6$ (per gate)

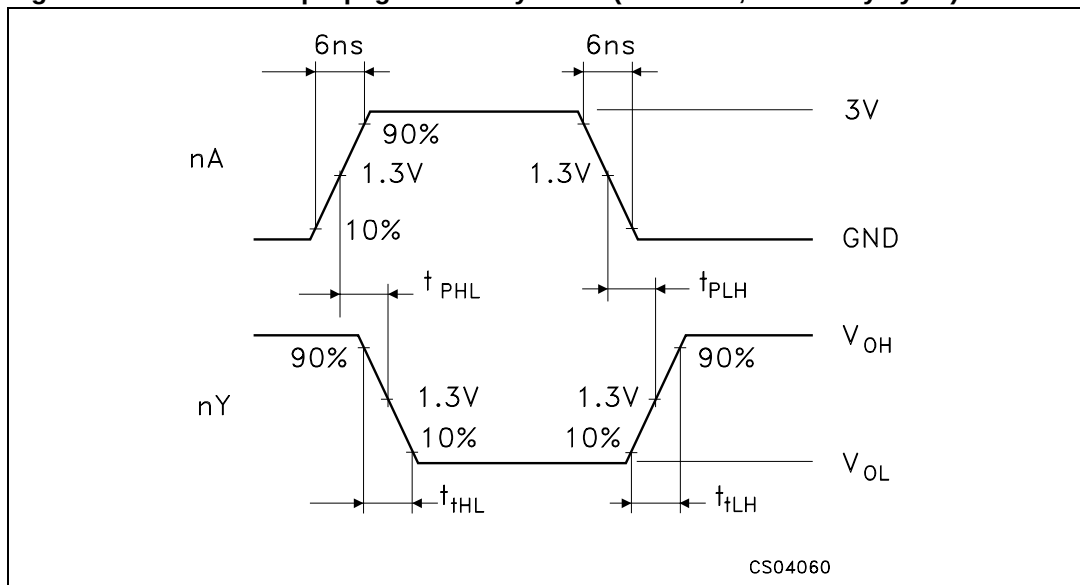
3 Test circuit

Figure 3. Test circuit



1. $C_L = 50\text{pF}$ or equivalent (includes jig and probe capacitance)
2. $R_T = Z_{OUT}$ of pulse generator (typically 50Ω)

Figure 4. Waveform: propagation delay times ($f = 1\text{ MHz}$; 50 % duty cycle)



4 Package mechanical data

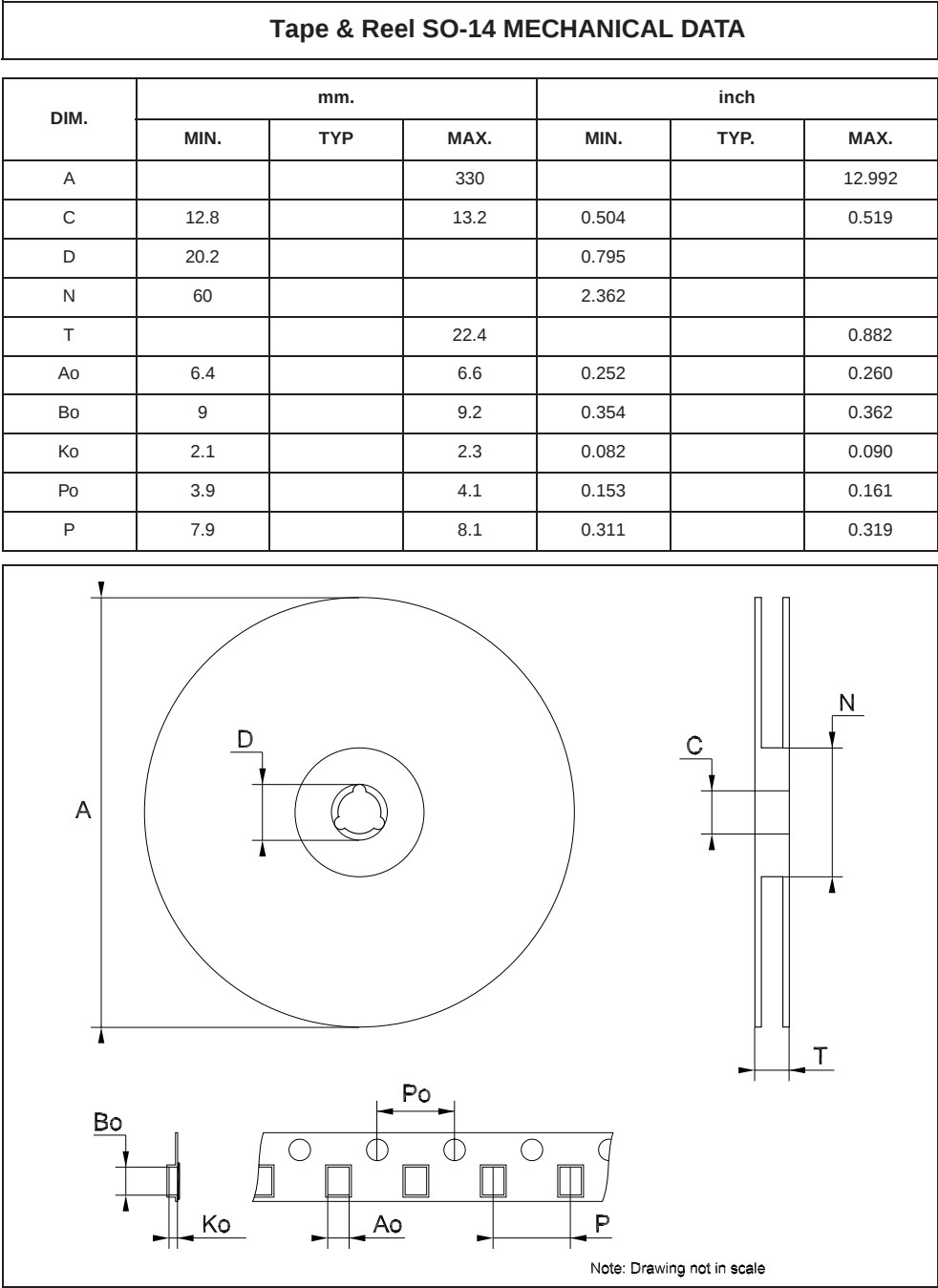
In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

Plastic DIP-14 MECHANICAL DATA						
DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	1.39		1.65	0.055		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		15.24			0.600	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z	1.27		2.54	0.050		0.100

The diagram illustrates the mechanical specifications of a Plastic DIP-14 package. It includes three views: a top view, a side view, and a bottom view. The top view shows the package body with pins on both sides. Dimensions labeled include 'a1' (pin height), 'B' (pin pitch), 'b' (pin width), 'b1' (pin thickness), 'D' (total width), 'e' (pin spacing), 'e3' (total pin length), 'F' (package height), 'I' (pin length), 'L' (package length), and 'Z' (pin offset). The side view shows the package profile with dimensions 'E' (body width) and 'b1' (pin thickness). The bottom view shows the package footprint with pins on both sides, labeled with pin numbers 1, 7, 8, and 14. The identifier 'P001A' is located in the bottom right corner of the diagram area.

SO-14 MECHANICAL DATA						
DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.75			0.068
a1	0.1		0.2	0.003		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1	45° (typ.)					
D	8.55		8.75	0.336		0.344
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		7.62			0.300	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.68			0.026
S	8° (max.)					

The diagram illustrates the mechanical specifications of the SO-14 package. It includes three views: a top view showing the 14 pins and dimensions D, M, F, and pin numbers 1, 7, 8, 14; a side view showing dimensions A, a1, a2, b, b1, C, c1, and the lead angle S; and a bottom view showing dimensions L, G, and E. The package is labeled PO13G.



5 Revision history

Table 9. Document revision history

Date	Revision	Changes
July-2001	1	Initial release.
23-May-2008	2	Document converted and restructured to new template. Removed: M74HC04M1R and M74HCT04TTR order codes. Added: tape and reel specifications for SO-14 package.